

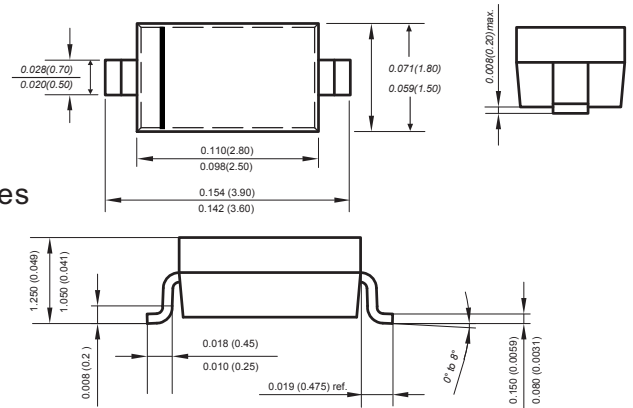
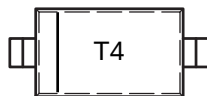
FEATURES

- ✧ For surface mounted applications
- ✧ Glass Passivated Chip Junction
- ✧ Fast reverse recovery time
- ✧ Ideal for automated placement
- ✧ Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ✧ Case: SOD-123
- ✧ Terminals: Solderable per MIL-STD-750, Method 2026
- ✧ Approx. Weight: 16mg/0. 00056oz

Marking



SOD-123

Dimensions in inches and (millimeters)

Absolute Maximum Ratings at 25 °C

Parameter	Symbols	1N4148W	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	V
Maximum RMS voltage	V_{RMS}	75	V
Continuous Forward Current	I_F	300	mA
Non-reptitive Peak Forward Surge Current at 1ms	I_{FSM}	4	A
Total Power Dissipation	P_{tot}	400	mW
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150	°C

Characteristics at $T_a = 25\text{ °C}$

Parameter	Symbols	1N4148W	Units
Reverse Breakdown Voltage at $I_R = 1\mu A$	$V_{(BR)R}$	75	V
Maximum Forward Voltage at 1 mA at 10 mA at 50 mA at 150 mA at 300 mA	V_F	0.715 0.855 1.00 1.25 1.5	V
Peak Reverse Current at $V_R = 20V$ $T_j = 25\text{ °C}$ at $V_R = 75V$ $T_j = 25\text{ °C}$ at $V_R = 25V$ $T_j = 150\text{ °C}$ at $V_R = 75V$ $T_j = 150\text{ °C}$	I_R	0.025 1 30 50	μA
Typical Junction Capacitance $f = 1MHz, V_R = 4V$	C_j	5	pF
Maximum Reverse Recovery Time ⁽¹⁾	t_{rr} Typical	8	ns

(1) Measured with $I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A$



Fig.1 Power Derating Curve

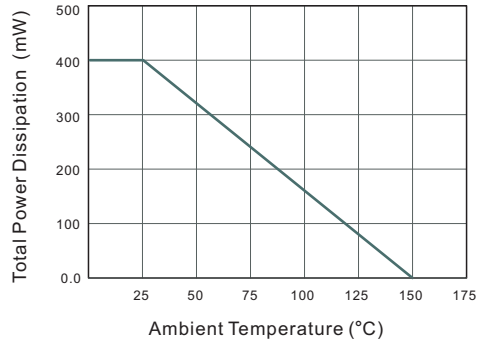


Fig.2 Typical Reverse Characteristics

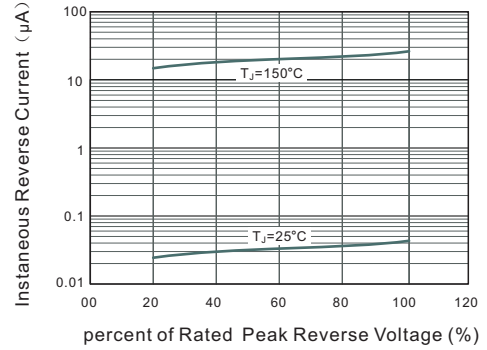


Fig.3 Typical Instaneous Forward Characteristics

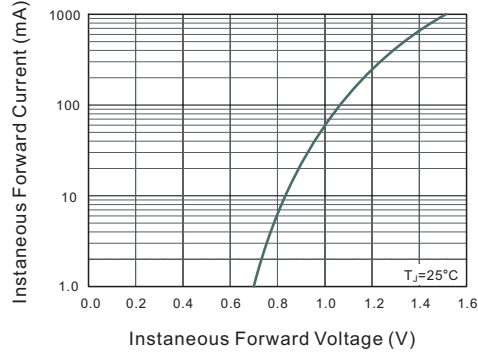


Fig.4 Typical Junction Capacitance

